Elektronische Bauelemente

SM320HT~SM3100HT

Voltage 20V ~ 100V

3.0 Amp Surface Mount Schottky Barrier Rectifiers

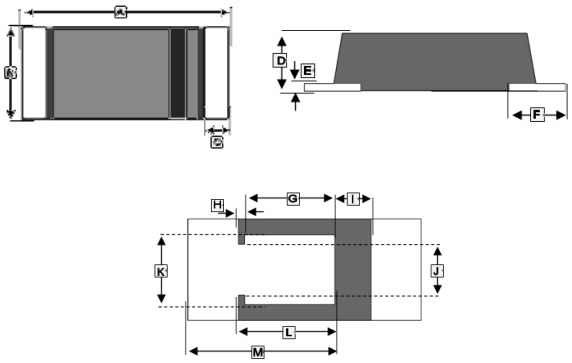
RoHS Compliant Product

A suffix of “-C” specifies halogen-free and RoHS Compliant

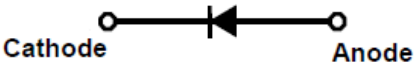
FEATURES

- Batch process design, excellent power dissipation offers better reverse leakage current and thermal resistance.
- Low profile surface mounted application in order to optimize board space.
- Low power loss, high efficiency.
- High current capability, low forward voltage drop.
- High surge capability
- Guarding for overvoltage protection
- Ultra high-speed switching
- Silicon epitaxial planar chip, metal silicon junction
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

SOD-123HT



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	3.3	3.7	H	0.6 TYP.	
B	1.4	1.8	I	0.6	0.8
C	0.3 TYP.		J	0.75	0.85
D	0.6	1.0	K	1.0	1.2
E	0.1 TYP.		L	1.1	1.3
F	0.8 TYP.		M	1.9	2.1
G	1.0	1.2			



MECHANICAL DATA

- Epoxy:UL94-V0 rated flame retardant
- Case : Molded plastic, SOD-123HT
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity : Indicated by cathode band
- Mounting Position : Any
- Weight : Approximated 0.011 gram

MARKING

Product	Marking Code	Product	Marking Code
SM320HT	32	SM380HT	38
SM340HT	34	SM3100HT	310
SM360HT	36		

PACKAGE INFORMATION

Package	MPQ	Leader Size
SOD-123HT	3K	7 inch

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS(T_A=25℃ unless otherwise specified)

Parameter		Symbol	Part Number					Unit
			SM320HT	SM340HT	SM360HT	SM380HT	SM3100HT	
Maximum Repetitive Peak Reverse Voltage		V_{RRM}	20	40	60	80	100	V
Maximum RMS Voltage		V_{RMS}	14	28	42	56	70	V
Continuous reverse voltage		V_R	20	40	60	80	100	V
Maximum Average Forward Rectified Current, See Fig.1		I_O	3					A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load		I_{FSM}	50					A
Maximum Instantaneous Forward Voltage @ I_F=3A		V_F	0.55		0.7	0.85		V
Maximum Reverse Current	T_J=25℃	I_R	0.2					mA
	T_J=100℃		20					
Typical Junction Capacitance [1]		C_J	160					pF
Typical Thermal Resistance		$R_{\theta JC}$	35					℃ / W
Operating Temperature		T_J	-55~125		-55~150			℃
Storage Temperature		T_{STG}	-65~175					℃

Note:
1. f=1MHz and applied 4V DC reverse voltage.

CHARACTERISTIC CURVES

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

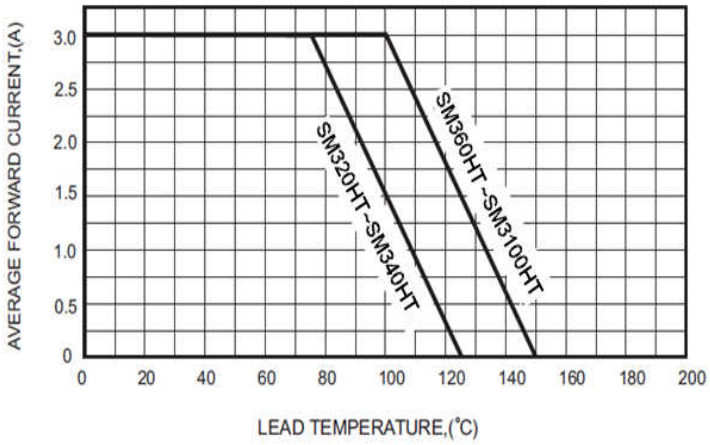


FIG.2-TYPICAL FORWARD CHARACTERISTICS

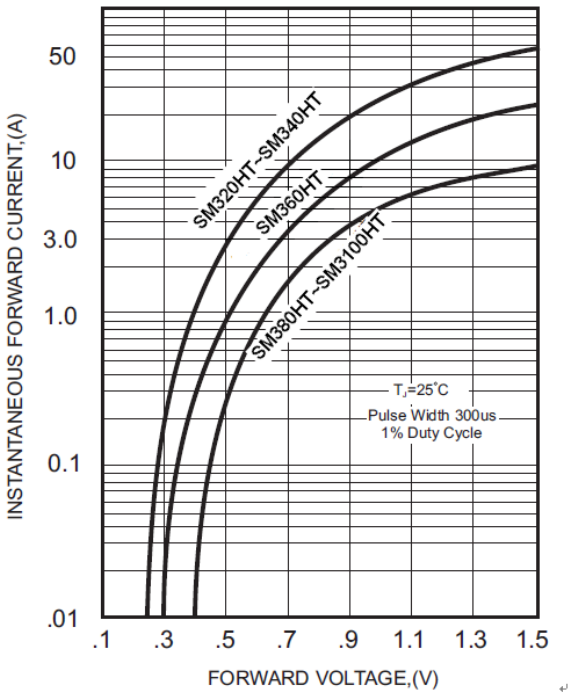


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

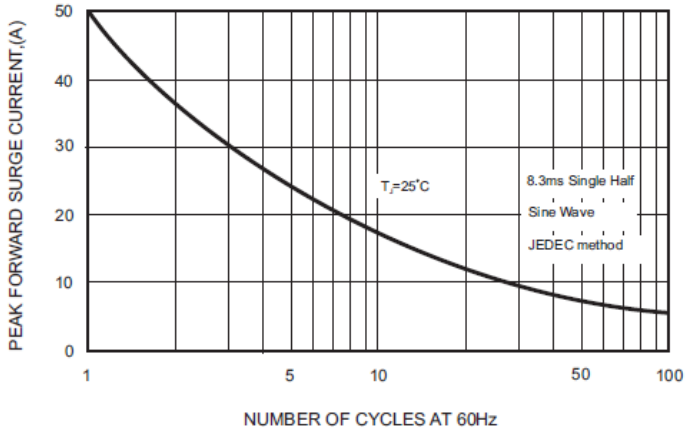


FIG.4-TYPICAL JUNCTION CAPACITANCE

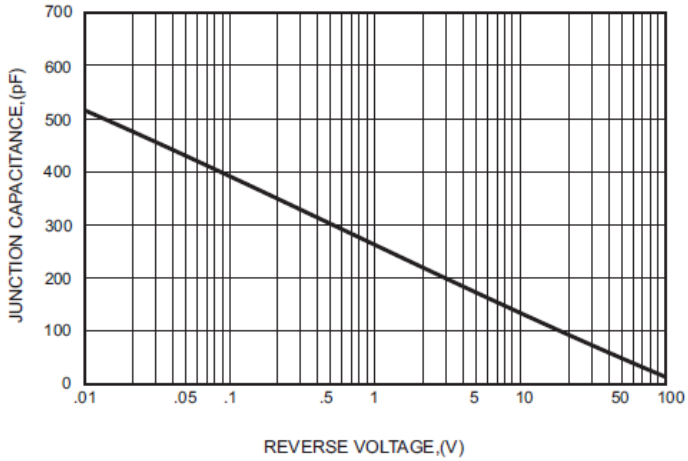


FIG.5 - TYPICAL REVERSE CHARACTERISTICS

